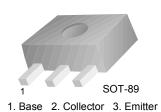
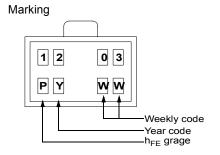


KSA1203 PNP Epitaxial Silicon Transistor

Low Frequency Power Amplifier

- · 3W Output application
- Collector Power Dissipation $P_C=1\sim2W$: Mounted on Ceramic Board
- Complement to KSC2883





Absolute Maximum Ratings T_a = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{CBO}	Collector-Base Voltage	-30	V
V_{CEO}	Collector-Emitter Voltage	-30	V
V_{EBO}	Emitter-Base Voltage	-5	V
I _C	Collector Current	-1.5	А
I_{B}	Base Current	-0.3	Α
P _C P _C *	Collector Power Dissipation	500 1,000	mW mW
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

^{*} Mounted on Ceramic Board (250mm $^2 \times 0.8$ mm)

Electrical Characteristics T_a = 25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = -10mA, I _B = 0	-30			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = -1 \text{mA}, I_C = 0$	-5			V
I _{CBO}	Collector Cut-off Current	V _{CB} = -30V, I _E = 0			-100	nA
I _{EBO}	Emitter Cut-off Current	$V_{BE} = -5V, I_{C} = 0$			-100	nA
h _{FE}	DC Current Gain	$V_{CE} = -2V, I_{C} = -500 \text{mA}$	100		320	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = -1.5A, I _B = -30mA			-2.0	V
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = -2V, I_{C} = -500 \text{mA}$			-1.0	V
f _T	Current Gain Bandwidth Product	V _{CE} = -2V, I _C = -500mA		120		MHz
C _{ob}	Output Capacitance	V _{CB} = -10V, I _E = 0, f = 1MHz			50	pF

h_{FE} Classification

Classification	0	Y
h _{FE}	100 ~ 200	160 ~ 320

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
1203	KSA1203	SOT-89	13"		4,000

Typical Performance Characteristics

Figure 1. Static Characteristic

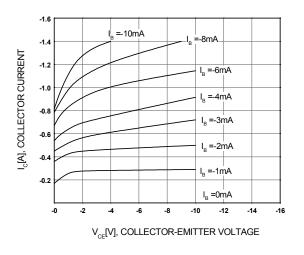


Figure 2. DC Current Gain

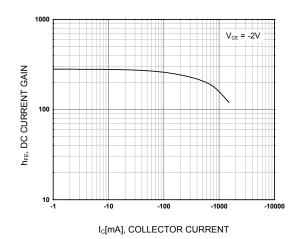


Figure 3. Collector-Emitter Saturation Voltage

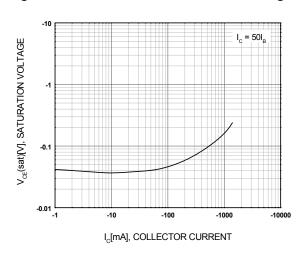


Figure 4. Base-Emitter On Voltage

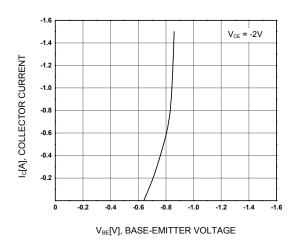


Figure 5. Safe Operating Area

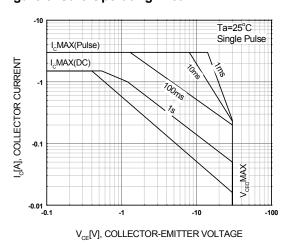
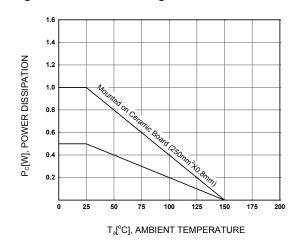


Figure 6. Power Derating

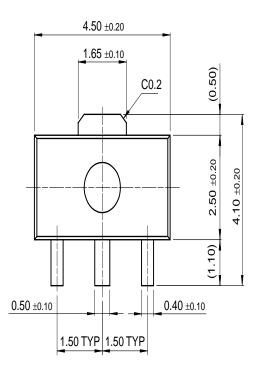
3

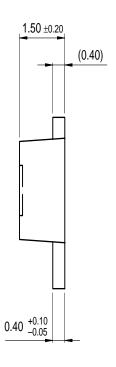


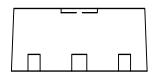
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Mechanical Dimensions

SOT-89







Dimensions in Millimeters

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SuperSOT™-6

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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Rev. I16